



P-CHANNEL ENHANCEMENT MODE MOSFET

Features

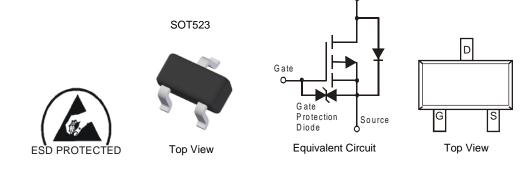
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

Mechanical Data

Case: SOT523

Drain

- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42
 leadframe. Solderable per MIL-STD-202, Method 208 (*3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2004TK-7	SOT523	3,000/Tape & Reel

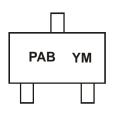
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



PAB = Product Type Marking Code YM = Date Code Marking Y = Year (ex: D = 2016) M = Month (ex: 9 = September)

Date Code Key

Year	2006	2007		2014	2015	2016	2017	2018	2019	2020	2021	2022
Code	T	U		В	C	D	E	F	G	H		 J
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	-20	V
Gate-Source Voltage			V _{GSS}	±8	V
Drain Current (Note 5)	(Note 5) Steady $T_A = +25^{\circ}C$ State $T_A = +85^{\circ}C$		Ι _D	-430 -310	mA
Pulsed Drain Current (Note 6)			I _{DM}	-750	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	150	mW
Thermal Resistance, Junction to Ambient	R ₀ JA	833	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

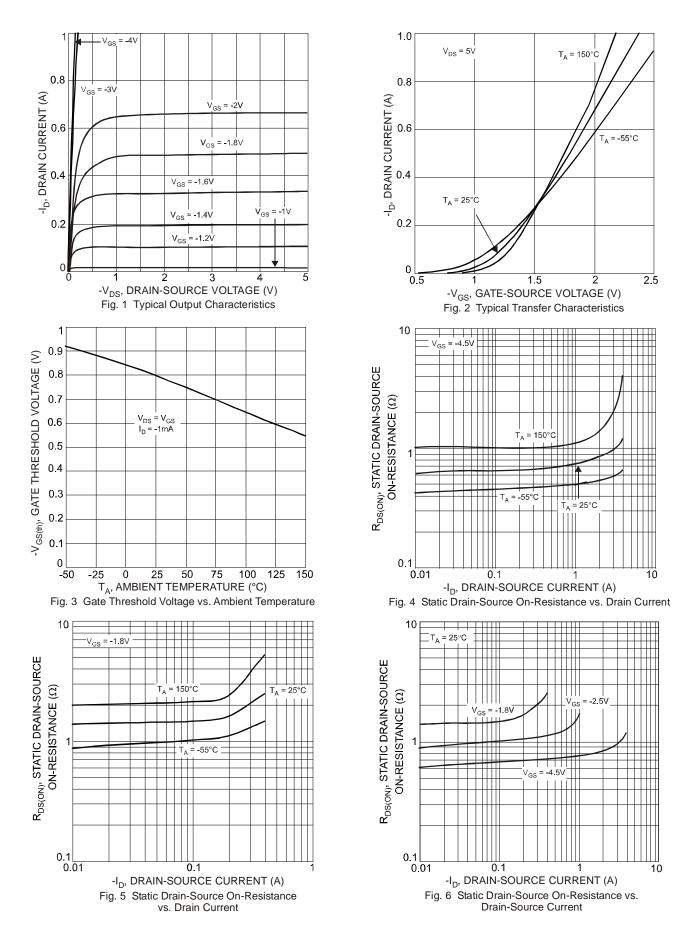
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_		V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	—	-1.0	μA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±1.0	μA	$V_{GS} = \pm 4.5 V$, $V_{DS} = 0 V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	-0.5		-1.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
			0.7	1.1		$V_{GS} = -4.5V, I_D = -430mA$	
Static Drain-Source On-Resistance	R _{DS} (ON)		1.1	1.6	Ω	$V_{GS} = -2.5V, I_D = -300mA$	
			1.7	2.4		$V_{GS} = -1.8V, I_D = -150mA$	
Forward Transfer Admittance	Y _{fs}	200	—	—	ms	$V_{DS} = 10V, I_D = 0.2A$	
Diode Forward Voltage (Note 7)	V _{SD}	_	_	-1.4	V	$V_{GS} = 0V, I_{S} = -115mA$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	Ciss	_		175	pF		
Output Capacitance	Coss			30	pF	$V_{DS} = -16V, V_{GS} = 0V$ - f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}		_	20	pF		

Notes:

5. Device mounted on FR-4 PCB.
 6. Pulse width ≤10µS, Duty Cycle ≤1%.
 7. Short duration pulse test used to minimize self-heating effect.

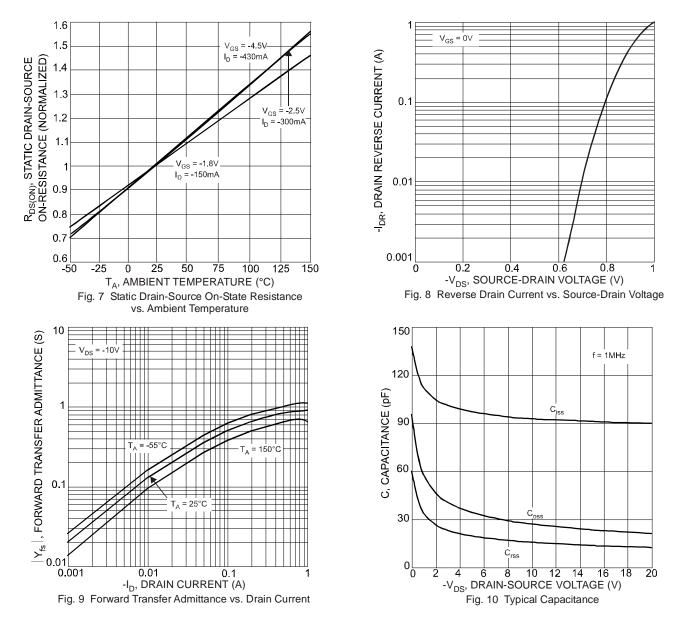


DMP2004TK



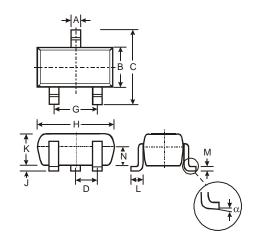


DMP2004TK



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

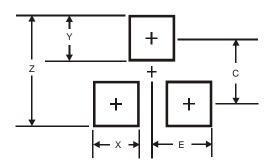


	SOT523							
Dim	Min	Max	Тур					
Α	0.15	0.30	0.22					
В	0.75	0.85	0.80					
С	1.45	1.75	1.60					
D		_	0.50					
G	0.90	1.10	1.00					
н	1.50	1.70	1.60					
J	0.00	0.10	0.05					
K	0.60	0.80	0.75					
L	0.10	0.30	0.22					
М	0.10	0.20	0.12					
N	0.45	0.65	0.50					
α	0°	8°						
All Dimensions in mm								



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
Z	1.8
Х	0.4
Y	0.51
С	1.3
E	0.7

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